

Rec'd PCT/PTO 20 MAR 2006

Attorney Docket No.: A-71721/MSS
 Dorsey & Whitney Docket No. 463035-314
 Serial No.: 10/525,122

DECLARATION FOR PATENT APPLICATION

As the below named inventor, I hereby declare that:

My residence, post office address and citizenship is as stated below next to my name;

I believe that I am the original, first and joint inventor of the subject matter which is claimed and for which a patent is sought on the invention entitled:

ATOMIC LAYER DEPOSITION OF HIGH-K METAL SILICATES

the specification of which:

☐ is attached hereto.
☒ was filed on:
 as Application No.:
 and was amended on:

August 18, 2003
PCT/US2003/025739
 (if applicable).

I have reviewed and understand the contents of the above-identified specification, including the claims, as amended by any amendment referred to above. I acknowledge the duty to disclose information which is material to patentability as defined in 37 C.F.R. § 1.56.

Prior Foreign Application(s)

I hereby claim foreign priority benefits under Title 35, United States Code, § 119(a)-(d) or § 365(b) of any foreign application(s) for patent or inventor's certificate, or § 365(a) of any PCT international application which designated at least one country other than the United States of America, listed below and have also identified below any foreign application(s) for patent or inventor's certificate having a filing date before that of the application on which priority is claimed:

Country	Application Number	Foreign Filing Date (DDMM/YYYY)	Priority Claimed		Certified Copy Attached	
			Yes <input type="checkbox"/>	No <input type="checkbox"/>	Yes <input type="checkbox"/>	No <input type="checkbox"/>
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Dorsey & Whitney LLP
 Intellectual Property Department
 565 California Street, Suite 1000
 San Francisco, California 94104-1613
 (650) 857-1717 (telephone); (650) 857-1288 (facsimile)
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4851-2687-46241

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Attorney Docket No.: A-71721/MSS
Dorsey & Whitney Docket No. 463035-814
Serial No.: 10/525,122

Prior Provisional Application(s)

I hereby claim priority under Title 35, United States Code § 119(e) of any United States provisional application(s) listed below:

Application Number	Date of Filing (day, month, year)
60/404,371	August 18, 2002

Prior United States Application(s)

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Application Number	Date of Filing (day, month, year)	Status - Patented, Pending, Abandoned

All correspondence and telephone communications should be addressed to Maria S. Swiatek at the address corresponding to Customer Number 32940 currently: DORSEY & WHITNEY LLP, Intellectual Property Department, 555 California Street, Suite 1000, San Francisco, California 94104-1513; telephone number (650) 857-1717; facsimile number (650) 857-1288.

I hereby declare that all statements made herein of my own knowledge are true and that all statements made on information and belief are believed to be true; and further that these statements were made with the knowledge that willful false statements and the like so made are punishable by fine and imprisonment, or both, under 18 U.S.C. § 1001, and that such willful false statements may jeopardize the validity of the application or any patent issuing thereon.

Dorsey & Whitney LLP
Intellectual Property Department
555 California Street, Suite 1000
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Attorney Docket No.: A-71721/MSS
 Dorsey & Whitney Docket No. 463035-814
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Signature

Date

3/14/06

Full Name of

First Inventor:

LEE

Sang-In

(Family Name)

(First Given Name)

(Second Given Name)

Citizenship:

Citizen of South Korea

Residence:

Cupertino, California

CA

Post Office

Address:

22608 San Juan Road

Cupertino, California 95014

Signature

Date

Full Name of

Second Inventor:

SENZAKI

Yoshihide

(Family Name)

(First Given Name)

(Second Given Name)

Citizenship:

Citizen of Japan

Residence:

Aptos, California

CA

Post Office

Address:

400 Clubhouse Drive

Aptos, California 95003

Signature

Date

Full Name of

Third Inventor:

LEE

Sang-Kyoo

(Family Name)

(First Given Name)

(Second Given Name)

Citizenship:

Citizen of Korea

Residence:

Suhcho-Gu, Seoul

KRX

Post Office

Address:

#200, 17-22 Yangjae 1 Dong

Suhcho-Gu, Seoul KOREA

Dorsey & Whitney LLP
 Intellectual Property Department
 556 California Street, Suite 1000
 San Francisco, California 94104-1513
 (650) 857-1717 (telephone); (650) 857-1208 (facsimile)

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Intellectual Property Department
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San Francisco, California 94104-1513
(650) 857-1717 (telephone); (650) 857-1288 (facsimile)

Signature _____ Date _____

Full Name of
First Inventor: LEE Sang-In
(Family Name) (First Given Name) (Second Given Name)
Citizenship: Citizen of South Korea
Residence: Cupertino, California
Post Office
Address: 22608 San Juan Road
Cupertino, California 95014

Signature  _____ Date 2-24-2006

Full Name of
Second Inventor: SENZAKI Yoshihide
(Family Name) (First Given Name) (Second Given Name)
Citizenship: Citizen of Japan
Residence: Aptos, California
Post Office
Address: 400 Clubhouse Drive
Aptos, California 95003

Signature _____ Date _____

Full Name of
Third Inventor: LEE Sang-Kyoo
(Family Name) (First Given Name) (Second Given Name)
Citizenship: Citizen of Korea
Residence: Suhcho-Gu, Seoul
Post Office
Address: #200, 17-22 Yangjae 1 Dong
Suhcho-Gu, Seoul KOREA

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Dorsey & Whitney LLP
 Intellectual Property Department
 656 California Street, Suite 1000
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Signature _____ Date _____
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Citizenship: Citizen of Japan
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Aptos, California 95003

Signature Lee Sangkyoo Date 2006.3.9
Full Name of
Third Inventor: LEE Sang-Kyoo
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Suhcho-Gu, Seoul KOREA

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